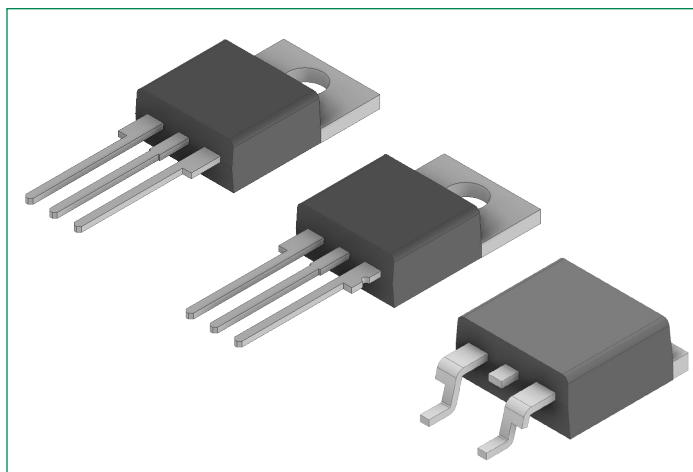


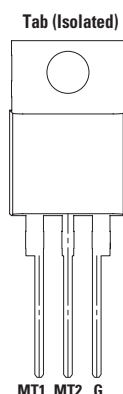
Qxx15xx and Qxx16xHx Series

15 A Standard and 16 A Alternistor (High Commutation) TRIACs

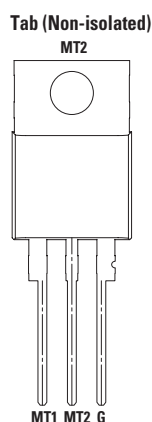


Pinout Diagram

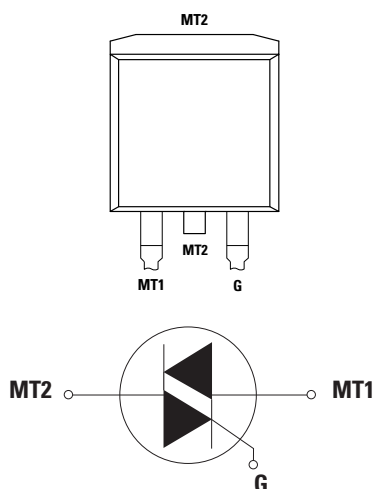
TO-220 (L-Package)



TO-220 (R-Package)



TO-263



MT1: Main Terminal 1; **MT2:** Main Terminal 2; **G:** Gate

Description

This 15 A and 16 A bi-directional solid state switch series is designed for AC switching and phase control applications. Standard type devices normally operate in Quadrants I & III triggered from AC line.

Standard Alternistor TRIAC components operate with in-phase signals in Quadrants I or III and ONLY unipolar negative gate pulses for Quadrant II or III. The Alternistor TRIAC will not operate in Quadrant IV.

Features

- RoHS-compliant
- Glass-passivated junctions
- Voltage capability up to 1000 V
- Surge capability up to 200 A
- The L package has an isolation rating of 2500 V_{RMS}
- Limited RFI generation, depending on activation point in sine wave
- Recognized to UL 1557 as an Electrically Isolated Semiconductor Device (L package: file number E71639)

Benefits

- Requires only a small gate activation pulse in each half-cycle
- Solid-state switching eliminates arcing or contact bounce that creates voltage transients
- Internally constructed isolated packages provide ease of heat sinking with highest isolation voltage
- No contacts to wear out from switching events

Applications

- AC switching and phase control applications such as heating, lighting, and motor speed control
- Power tools
- White goods appliances
- Alternistor TRIACs (no snubber required) used in applications with extremely inductive loads requiring highest commutation performance.

Product Summary

Characteristic	Value	Unit
$I_{T(RMS)}$	15 or 16	A
V_{DRM}/V_{RRM}	400, 600, 800, or 1000	V
$I_{GT(Q1)}$	10, 20, 35, 50, or 80	mA

Qxx15xx and Qxx16xHx Series

15 A Standard and 16 A Alternistor (High Commutation) TRIACs

Maximum Ratings - Standard TRIAC

Symbol	Characteristics	Conditions			Value	Units
I _{T(RMS)}	On-state RMS Current	Qxx15Ly	T _C = 80 °C	full sine wave	15	A
		Qxx15Ry/ Qxx15Ny	T _C = 90 °C			
I _{TSM}	Non-repetitive Surge Peak On-state Current	f = 50 Hz, t = 20 ms	T _{vi} initial = 25 °C, full cycle		167	A
		f = 60 Hz, t = 16.7 ms			200	
I ² t	I ² t Value for Fusing	t _p = 8.3 ms			166	A ² s
di/dt _(cr)	Critical Rate of Rise of On-state Current	f = 120 Hz, T _{vi} = 125 °C			100	A/μs
I _{GTM}	Peak Gate Trigger Current	t _p = 20 μs, T _{vi} = 125 °C			4	A
P _{G(AV)}	Average Gate Power Dissipation	T _{vi} = 125 °C			0.5	W
T _{stg}	Storage Temperature Range	–			–40 to 150	°C
T _{vi}	Operating Junction Temperature Range	–			–40 to 125	°C

xx = voltage/10; y = sensitivity

Maximum Ratings - Alternistor TRIAC (3 Quadrants)

Symbol	Characteristics	Conditions			Value	Units
I _{T(RMS)}	On-state RMS Current	Qxx16Ly	T _C = 80 °C	full sine wave	16	A
		Qxx16Ry/ Qxx16Ny	T _C = 90 °C			
I _{TSM}	Non-repetitive Surge Peak On-state Current	f = 50 Hz, t = 20 ms	T _{vi} initial = 25 °C, full cycle		167	A
		f = 60 Hz, t = 16.7 ms			200	
I ² t	I ² t Value for Fusing	t _p = 8.3 ms			166	A ² s
di/dt _(cr)	Critical Rate of Rise of On-state Current	f = 120 Hz, T _{vi} = 125 °C			100	A/μs
I _{GTM}	Peak Gate Trigger Current	t _p = 20 μs, T _{vi} = 125 °C			4	A
P _{G(AV)}	Average Gate Power Dissipation	T _{vi} = 125 °C			0.5	W
T _{stg}	Storage Temperature Range	–			–40 to 150	°C
T _{vi}	Operating Junction Temperature Range	–			–40 to 125	°C

xx = voltage/10; y = sensitivity

Electrical Characteristics ($T_{vj} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified) — Standard TRIAC

Symbol	Characteristics	Conditions	Value			Units
			Min.	Typ.	Max.	
I_{GT}	DC Gate Trigger Current	$V_D = 12\text{ V}$, $R_L = 60\text{ }\Omega$	I – II – III	–	50	mA
			IV	–	90	
V_{GT}	DC Gate Trigger Voltage	$V_D = 12\text{ V}$, $R_L = 60\text{ }\Omega$	I – II – III	–	1.3	V
			IV	–	1.8	
V_{GD}	Gate Non-trigger Voltage	$V_D = V_{DRM}$, $R_L = 3.3\text{ k}\Omega$, $T_{vj} = 125\text{ }^{\circ}\text{C}$	ALL	0.2	–	V
I_H	Holding Current	$I_T = 100\text{ mA}$	–	–	70	mA
$dv/dt_{(cr)}$	Critical Rate-of-rise of Off-state Voltage	$V_D = V_{DRM}$, Gate Open, $T_{vj} = 125\text{ }^{\circ}\text{C}$	400 V	275	–	V/ μs
			600 V	225	–	
			800 V	200	–	
		$V_D = 2/3 V_{DRM}$, Gate Open, $T_{vj} = 100\text{ }^{\circ}\text{C}$	1000 V	200	–	
$dv/dt_{(com)}$	Critical Rate-of-rise of Commutation Voltage	$(di/dt)_c = 8.1\text{ A/ms}$, $T_{vj} = 125\text{ }^{\circ}\text{C}$	–	4	–	V/ μs
t_{gt}	Turn-on Time	$I_G = 2 \times I_{GT}$, $P_W = 15\text{ }\mu\text{s}$, $I_T = 22.6\text{ A}_{pk}$	–	4	–	μs

Electrical Characteristics ($T_{vj} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified) — **Alternistor TRIAC** (3 Quadrants)

Symbol	Characteristics	Conditions	Quadrant		Value			Units
					Min.	Typ.	Max.	
I _{GT}	DC Gate Trigger Current	V _D = 12 V, R _L = 60 Ω	I – II – III	Qxx16xH2	–	–	10	mA
				Qxx16xH3	–	–	20	
				Qxx16xH4	–	–	35	
				Qxx16xH6	–	–	80	
				Qxx15x6	–	–	80	
V _{GT}	DC Gate Trigger Voltage	V _D = 12 V, R _L = 60 Ω	I – II – III	All	–	–	1.3	V
V _{GD}	Gate Non-trigger Voltage	V _D = V _{DRM} , R _L = 3.3 kΩ, T _{vj} = 125 °C	I – II – III	All	0.2	–	–	V
I _H	Holding Current	I _T = 100 mA		Qxx16xH2	–	–	15	mA
				Qxx16xH3	–	–	35	
				Qxx16xH4	–	–	50	
				Qxx16xH6	–	–	70	
				Qxx15x6	–	–	70	
dv/dt _(cr)	Critical Rate-of-rise of Off-state Voltage	V _D = V _{DRM} , Gate Open, T _{vj} = 125 °C	400 V	Qxx16xH2	200	–	–	V/μs
				Qxx16xH3	350	–	–	
				Qxx16xH4	475	–	–	
				Qxx16xH6	925	–	–	
				Qxx15x6	–	–	–	
			600 V	Qxx16xH2	150	–	–	
				Qxx16xH3	250	–	–	
				Qxx16xH4	400	–	–	
				Qxx16xH6	850	–	–	
				Qxx15x6	600	–	–	
			800 V	Qxx16xH2	100	–	–	
				Qxx16xH3	200	–	–	
				Qxx16xH4	350	–	–	
				Qxx16xH6	475	–	–	
				Qxx15x6	–	–	–	
		V _D = 2/3 V _{DRM} , Gate Open, T _{vj} = 100 °C	1000 V	Qxx16xH2	100	–	–	
				Qxx16xH3	200	–	–	
				Qxx16xH4	300	–	–	
				Qxx16xH6	350	–	–	
				Qxx15x6	–	–	–	
dv/dt _(com)	Critical Rate-of-rise of Commutation Voltage	(di/dt) _c = 8.6 A/ms, T _{vj} = 125 °C		Qxx16xH2	2	–	–	V/μs
				Qxx16xH3	20	–	–	
				Qxx16xH4	25	–	–	
				Qxx16xH6	30	–	–	
				Qxx15x6	25	–	–	
t _{gt}	Turn-on Time	I _G = 2 × I _{GT} , P _W = 15 μs, I _T = 22.6 A _{pk}		Qxx16xH2	–	3	–	μs
				Qxx16xH3	–	3	–	
				Qxx16xH4	–	3	–	
				Qxx16xH6	–	5	–	
				Qxx15x6	–	5	–	

Static Characteristics (applicable to 15 A and 16 A devices)

Symbol	Characteristics	Conditions		Maximum Value	Units
V_{TM}	Peak On-state Voltage	15 A Device: $I_T = 21.2 \text{ A}$ $t_p = 380 \text{ } \mu\text{s}$	—	1.6	V
		16 A Device: $I_T = 22.6 \text{ A}$ $t_p = 380 \text{ } \mu\text{s}$			—
I_{DRM}/I_{RRM}	Off-state Current, Peak Repetitive	$V_D = V_{DRM}/V_{RRM}$	$T_{vj} = 25 \text{ } ^\circ\text{C}$	400-1000 V	5 μA
			$T_{vj} = 125 \text{ } ^\circ\text{C}$	400-800 V	2 mA
			$T_{vj} = 100 \text{ } ^\circ\text{C}$	1000 V	3

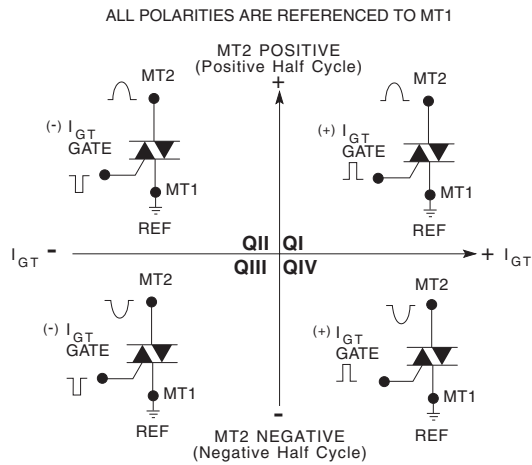
Thermal Characteristics (applicable to 15 A and 16 A devices)

Symbol	Characteristics		Value	Units
$R_{th(j-c)}$	Thermal Resistance, Junction to Case (AC)	Qxx15Ry/ Qxx15Ny/ Qxx16RHx/ Qxx16NHx	1.7	K/W
		Qxx15Ly/ Qxx16LHx	2.1	
$R_{th(j-a)}$	Thermal Resistance, Junction to Ambient	Qxx15Ry/ Qxx16RHx	45	K/W
		Qxx15Ly/ Qxx16LHx	50	

xx = voltage/10; y = sensitivity

Characteristic Curves

Figure 1. Definition of Quadrants



Note: Alternistors will not operate in QIV

Fig. 2. Normalized DC Gate Trigger Current for all Quadrants vs. Junction Temperature

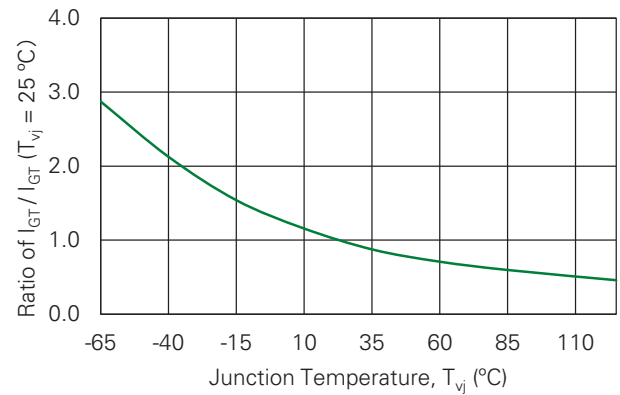


Fig. 3. Normalized DC Holding Current vs. Junction Temperature

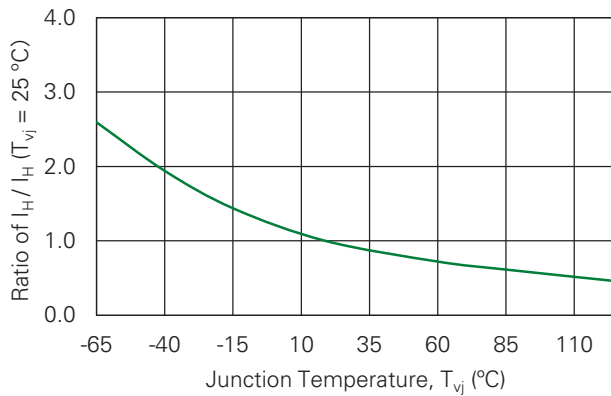


Fig. 4. Normalized DC Gate Trigger Voltage for all Quadrants vs. Junction Temperature

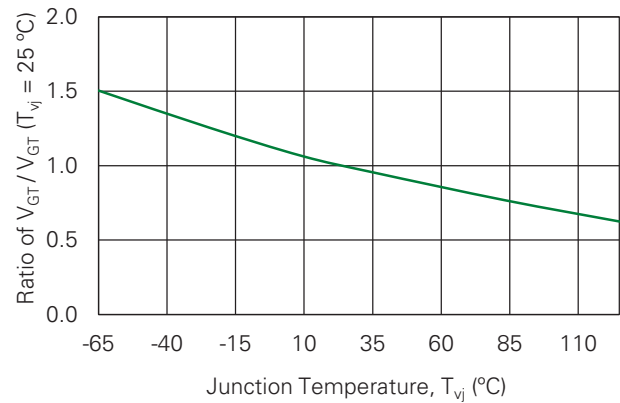


Fig. 5. Typical Power Dissipation vs. RMS On-state Current

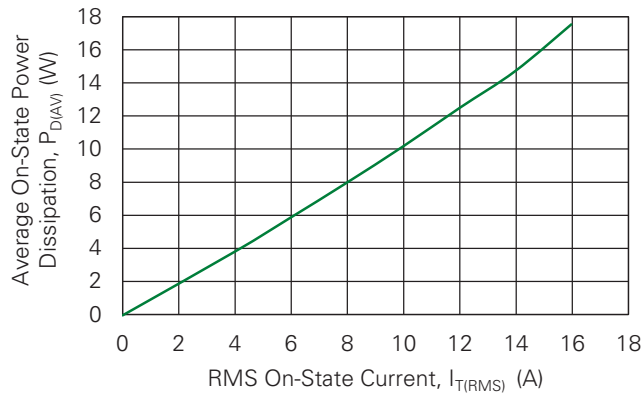


Fig. 6. Maximum Allowable Case Temperature vs. On-state Current (15 A Devices)

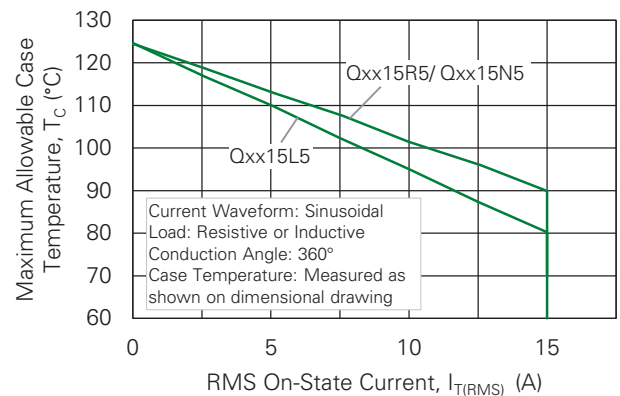
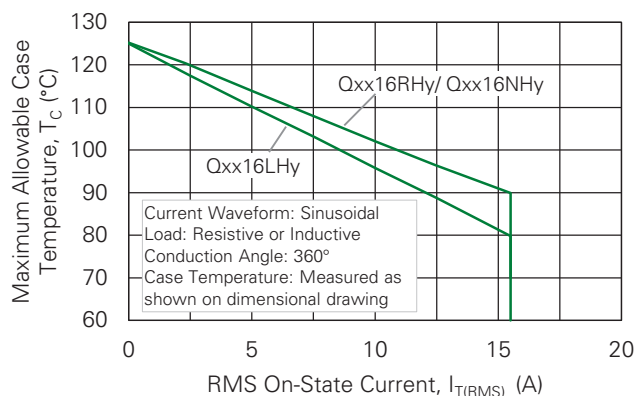
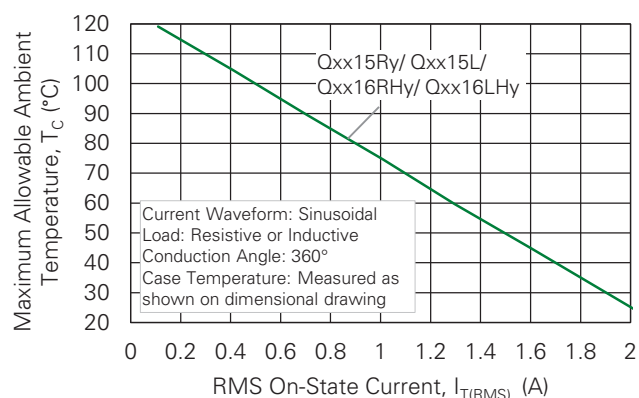
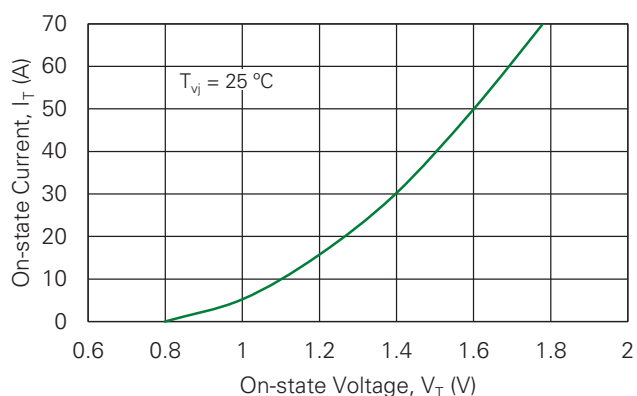
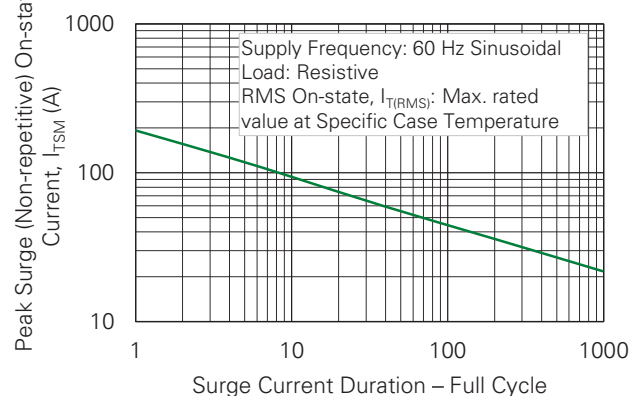
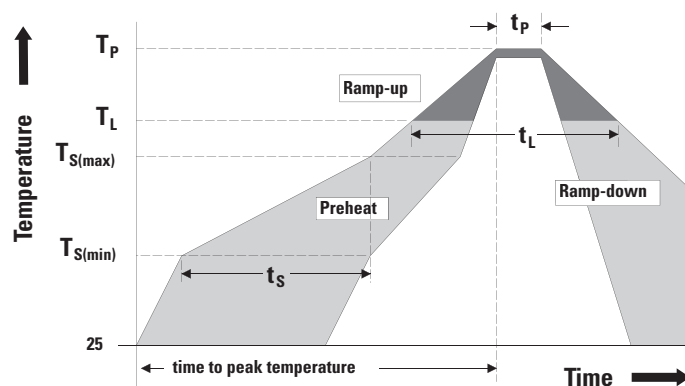


Fig. 7. Maximum Allowable Case Temperature vs. On-state Current (16 A Devices)**Fig. 8. Maximum Allowable Ambient Temperature vs. On-state Current****Fig. 9. Typical On-state Current vs. On-state Voltage****Fig. 10. Surge Peak On-state Current vs. Number of Cycles****Notes:**

- Gate control may be lost during and immediately following surge current interval.
- Overload may not be repeated until junction temperature has returned to steady-state rated value.

Soldering Parameters

Characteristic		Value
Reflow Condition		Pb – Free assembly
Pre-heat	Temperature Min ($T_{s(min)}$)	150 °C
	Temperature Max ($T_{s(max)}$)	200 °C
	Time (min to max) (t_s)	60 – 180 secs
Average ramp up rate (Liquidus Temp) (T_L) to peak		5 °C/second max
$T_{s(max)}$ to T_L - Ramp-up Rate		5 °C/second max
Reflow	Temperature (T_L) (Liquidus)	217 °C
	Time (t_L)	60 – 150 seconds
Peak Temperature (T_P)		260 ^{+0/-5} °C
Time within 5 °C of actual peak Temperature (t_p)		20 – 40 seconds
Ramp-down Rate		5 °C/second max
Time 25 °C to peak Temperature (T_P)		8 minutes max
Do Not Exceed		280 °C



Physical Specifications

Characteristic	Value
Terminal Finish	100% Matte Tin-plated
Body Material	UL Recognized compound meeting flammability rating V-0
Terminal Material	Copper Alloy

Environmental Specifications

Test	Specifications and Conditions
AC Blocking	MIL-STD-750, M-1040, Cond A Applied Peak AC voltage @ 125 °C for 1008 hours
Temperature Cycling	MIL-STD-750, M-1051, 100 cycles; -40 °C to +150 °C; 15-min dwell-time
Temperature/Humidity	EIA / JEDEC, JESD22-A101, 1008 hours; 320 V - DC: 85 °C; 85% relative humidity
High Temperature Storage	MIL-STD-750, M-1031, 1008 hours; 150 °C
Low Temperature Storage	1008 hours; -40 °C
Resistance to Solder Heat	MIL-STD-750: Method 2031
Solderability	ANSI/J-STD-002: category 3, Test A
Lead Bend	MIL-STD-750, M-2036 Cond E

Packing Options

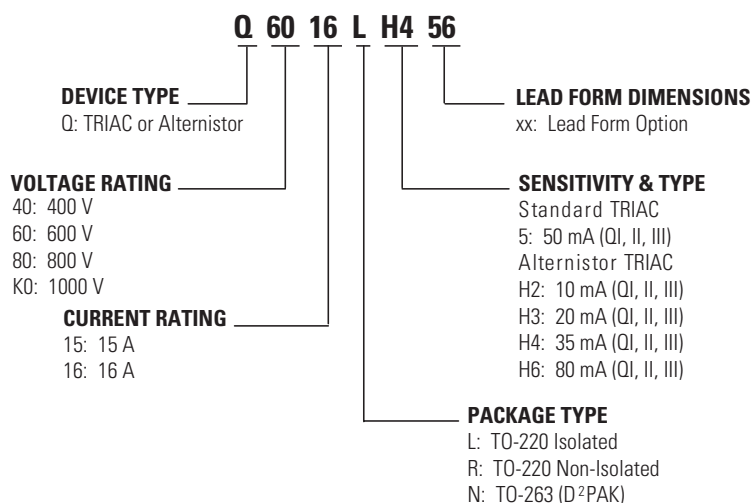
Part Number	Marking	Weight	Packing Mode	Base Quantity
Qxx15L/RyTP	Qxx15L/Ry	2.2 g	Tube Pack	1000 (50 per tube)
Qxx15NyTP	Qxx15Ny	1.6 g	Tube	1000 (50 per tube)
Qxx15NyRP	Qxx15Ny	1.6 g	Embossed Carrier	500
Qxx16L/RHyTP	Qxx16L/RHy	2.2 g	Tube Pack	1000 (50 per tube)
Qxx16NHyTP	Qxx16NHy	1.6 g	Tube	1000 (50 per tube)
Qxx16NHyRP	Qxx16NHy	1.6 g	Embossed Carrier	500

xx = voltage/10; y = sensitivity

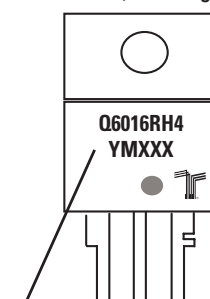
Product Selector

Part Number	Voltage				Gate Sensitivity Quadrants	Type	Package
	400 V	600 V	800 V	1000 V	I-II-III		
Qxx15L5	X	X	X	X	50 mA	Standard TRIAC	TO-220AB (L package)
Qxx15R5	X	X	X	X	50 mA	Standard TRIAC	TO-220AB (R package)
Qxx15N5	X	X	X	X	50 mA	Standard TRIAC	TO-263 (D ² PAK)
Qxx15L6	–	X	–	–	80 mA	Alternistor TRIAC	TO-220AB (L package)
Qxx16LH2	X	X	X	X	10 mA	Alternistor TRIAC	TO-220AB (L package)
Qxx16RH2	X	X	X	X	10 mA	Alternistor TRIAC	TO-220AB (R package)
Qxx16NH2	X	X	X	X	10 mA	Alternistor TRIAC	TO-263 (D ² PAK)
Qxx16LH3	X	X	X	X	20 mA	Alternistor TRIAC	TO-220AB (L package)
Qxx16RH3	X	X	X	X	20 mA	Alternistor TRIAC	TO-220AB (R package)
Qxx16NH3	X	X	X	X	20 mA	Alternistor TRIAC	TO-263 (D ² PAK)
Qxx16LH4	X	X	X	X	35 mA	Alternistor TRIAC	TO-220AB (L package)
Qxx16RH4	X	X	X	X	35 mA	Alternistor TRIAC	TO-220AB (R package)
Qxx16NH4	X	X	X	X	35 mA	Alternistor TRIAC	TO-263 (D ² PAK)
Qxx16LH6	X	X	X	X	80 mA	Alternistor TRIAC	TO-220AB (L package)
Qxx16RH6	X	X	X	X	80 mA	Alternistor TRIAC	TO-220AB (R package)
Qxx16NH6	X	X	X	X	80 mA	Alternistor TRIAC	TO-263 (D ² PAK)

Part Numbering and Marking

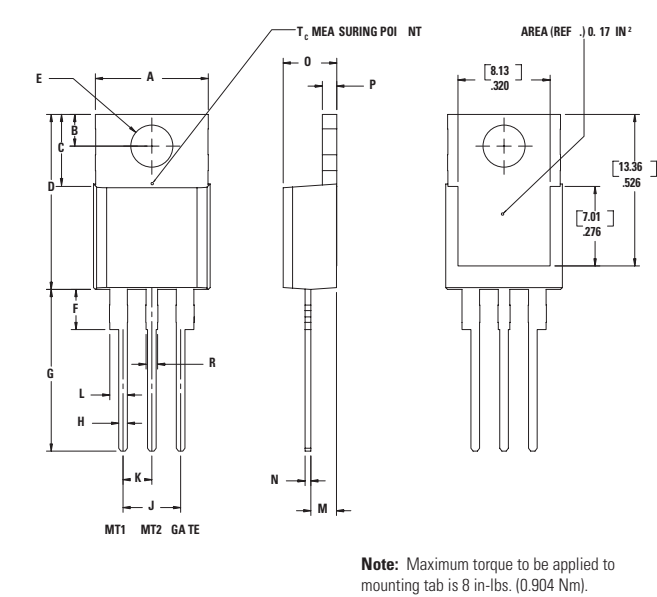


TO-220 AB - (L and R Package)
TO-263 AB - (N Package)



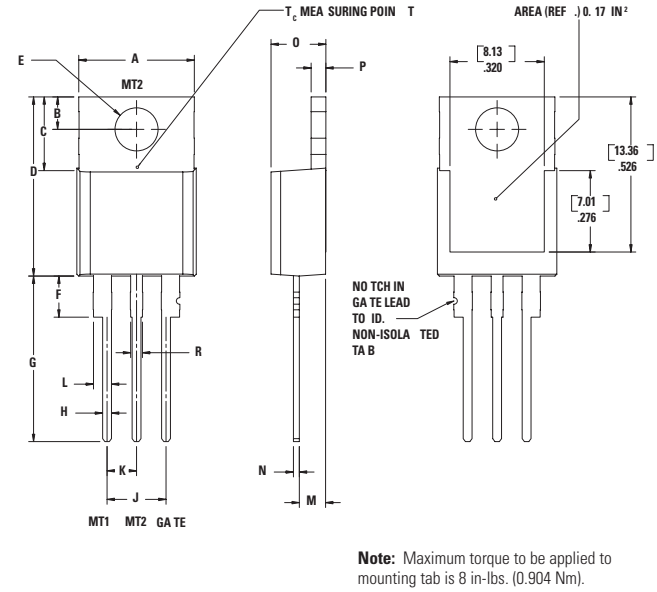
Date Code Marking
Y: Year Code
M: Month Code
XXX: Lot Trace Code

Package Dimensions TO-220AB (L Package) – Isolated Mounting Tab



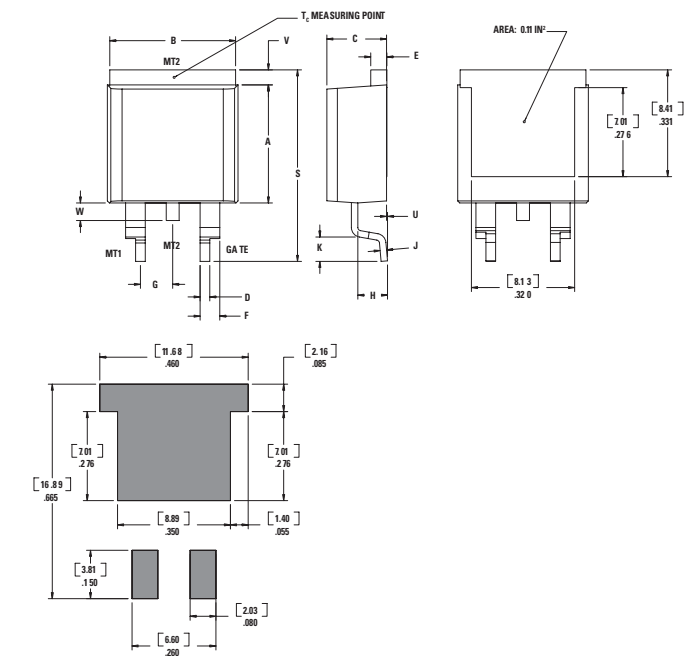
Symbol	Millimeters		Inches	
	Min.	Max.	Min.	Max
A	9.65	10.67	0.380	0.420
B	2.67	2.92	0.105	0.115
C	5.84	6.35	0.230	0.250
D	14.99	15.75	0.590	0.620
E	3.61	3.73	0.142	0.147
F	2.79	3.30	0.110	0.130
G	13.72	14.60	0.540	0.575
H	0.64	0.89	0.025	0.035
J	4.95	5.21	0.195	0.205
K	2.41	2.67	0.095	0.105
L	1.52	1.91	0.060	0.075
M	2.16	2.41	0.085	0.095
N	0.46	0.61	0.018	0.024
O	4.52	4.78	0.178	0.188
P	1.14	1.52	0.045	0.060
R	0.97	1.22	0.038	0.048

Package Dimensions TO-220AB (R Package) – Non-isolated Mounting Tab Common with Center Lead



Symbol	Millimeters		Inches	
	Min.	Max.	Min.	Max
A	9.65	10.67	0.380	0.420
B	2.67	2.92	0.105	0.115
C	5.84	6.35	0.230	0.250
D	14.99	15.75	0.590	0.620
E	3.61	3.73	0.142	0.147
F	2.79	3.30	0.110	0.130
G	13.72	14.60	0.540	0.575
H	0.64	0.89	0.025	0.035
J	4.95	5.21	0.195	0.205
K	2.41	2.67	0.095	0.105
L	1.52	1.91	0.060	0.075
M	2.16	2.41	0.085	0.095
N	0.46	0.61	0.018	0.024
O	4.52	4.78	0.178	0.188
P	1.14	1.52	0.045	0.060
R	0.97	1.22	0.038	0.048

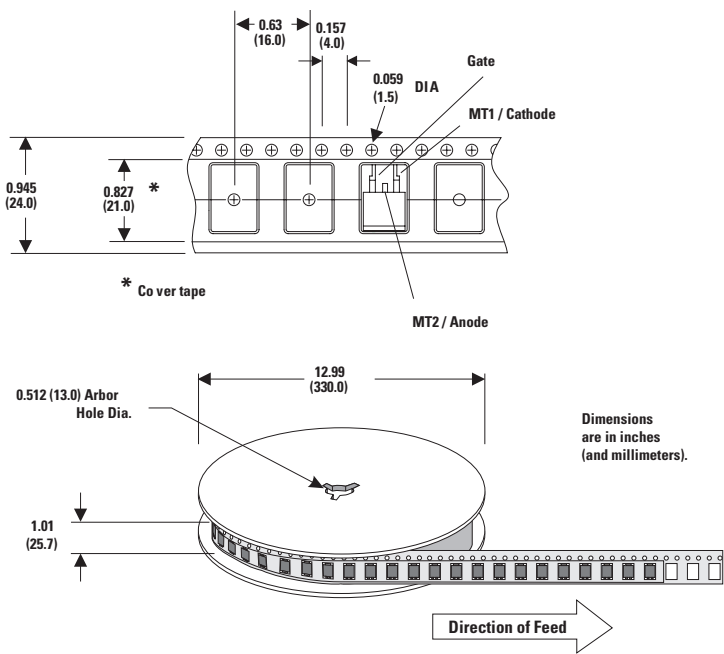
Package Dimensions TO-263 (N Package) – D²PAK Surface Mount



Symbol	Millimeters		Inches	
	Min.	Max.	Min.	Max
A	9.14	9.40	0.360	0.370
B	9.65	10.67	0.380	0.420
C	4.52	4.78	0.178	0.188
D	0.64	0.89	0.025	0.035
E	1.14	1.52	0.045	0.060
F	1.52	1.91	0.060	0.075
G	2.41	2.67	0.095	0.105
H	2.34	2.59	0.092	0.102
J	0.46	0.61	0.018	0.024
K	2.29	2.79	0.090	0.110
S	14.99	15.88	0.590	0.625
V	0.89	1.14	0.035	0.045
U	0.05	0.25	0.002	0.010
W	1.02	1.78	0.040	0.070

Reel Pack (RP) Specifications for TO-263 Embossed Carrier

Meets all EIA-481-2 Standards



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